



MPS6531



NPN General Purpose Amplifier

This device is designed for use as a medium power amplifier and switch requiring collector currents to 500 mA. Sourced from Process 19. See PN2222A for characteristics.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	5.0	V
Ic	Collector Current - Continuous	1.0	Α
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

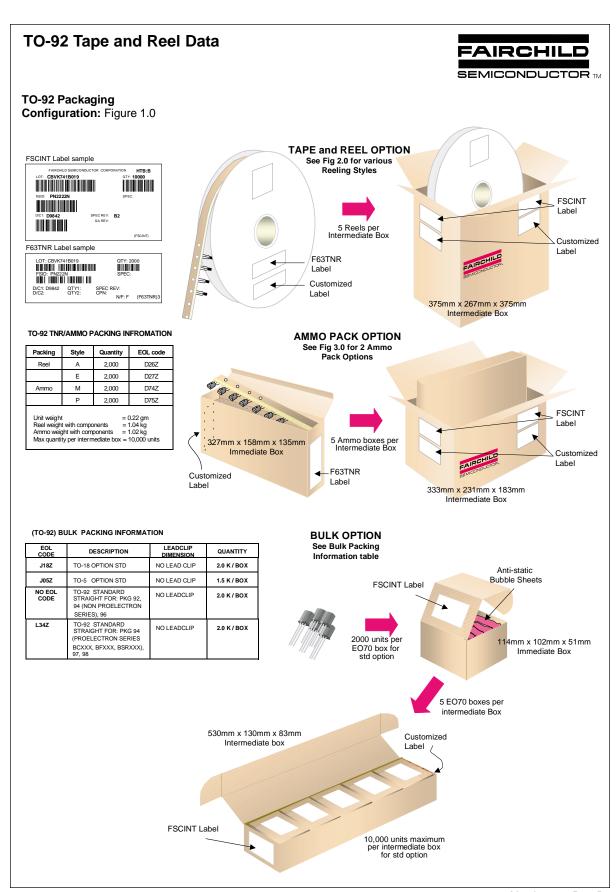
Symbol	Characteristic	Max	Units
		MPS6531	
P _D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

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NPN General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OEE CUA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{mA}, I_{\rm B} = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 10 \text{ µA}, I_E = 0$	60		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu\text{A}, I_C = 0$	5.0		V
I _{CBO}	Collector Cutoff Current	V _{CB} = 40 V, I _F = 0		50	nA
CBO		$V_{CB} = 40 \text{ V}, I_{E} = 0, T_{A} = 60 ^{\circ}\text{C}$		2.0	μΑ
	RACTERISTICS*	7 2		2.0	μА
ON CHAF		$V_{CB} = 40 \text{ V}, I_{E} = 0, T_{A} = 60 \text{ °C}$ $V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_{C} = 100 \text{ mA}$	60 90 50	2.0	μΑ
ON CHAF	RACTERISTICS*	$V_{CB} = 40 \text{ V}, I_{E} = 0, T_{A} = 60 ^{\circ}\text{C}$ $V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$			μA
	RACTERISTICS* DC Current Gain	$V_{CB} = 40 \text{ V}, I_{E} = 0, T_{A} = 60 \text{ °C}$ $V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_{C} = 100 \text{ mA}$ $V_{CE} = 10 \text{ V}, I_{C} = 500 \text{ mA}$	90	270	

^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

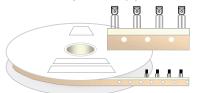


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TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)



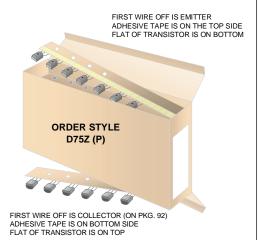
Style "A", D26Z, D70Z (s/h)

Machine Option "E" (J)

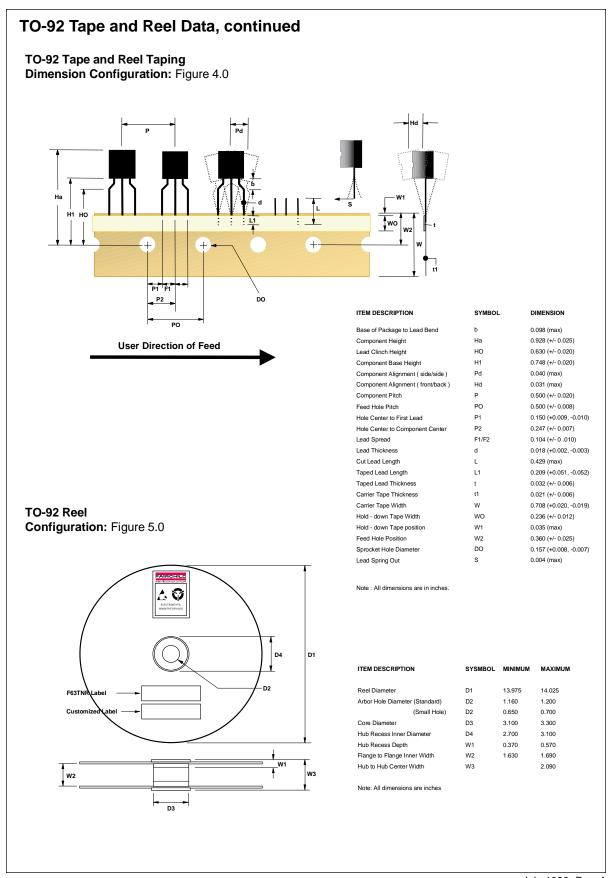
Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0





September 1999, Rev. B



TO-92 Package Dimensions FAIRCHILD SEMICONDUCTOR TM TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 0.185 4.70 0.170 4.32 TO-92 (92,94,96) 94 96 B F В В В D D 2 В S С G Ε Ø0.060 [Ø1.52] G В S С G 0.010 [0.254] DEEP 5.0°TYP.

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0.095 0.084 2.13

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